NSN 5961-01-342-0758

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view Online at https://aerobasegroup.com/nsn/5961-01-342-0/56
Inclosure Material:
Metal
Overall Length:
Between 0.975 inches and 1.218 inches
Function For Which Designed:
Switching
End Application:
Tactical air operations central an/tyq-2 (v) 1
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
To-59
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case and electrostatic sensitive
Overall Width Across Flats:
Between 0.424 inches and 0.437 inches
Thread Size:
0.190 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
80.0 breakdown voltage, collector-to-emitter, base open
Current Rating Per Characteristic:
5.00 amperes source cutoff current
Power Rating Per Characteristic:
20.0 watts small-signal input power, common-collector absolute
Transfer Ratio:
50.0 static forward current transfer ratio, common-emitter and 150.0 static forward current transfer ratio, common-emitter
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
Junction pattern arrangement: npn
Thread Series Designator:
Unf
Terminal Type And Quantity:
3 tab, solder lug

N/a

Shelf Life:

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Demilitarization:

No

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